

# A new class of high ZT doped bulk nanothermoelectrics through bottom-up synthesis

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- **Students and Post-Doctoral Associates**

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**Borca-Tasiuc group:** Dr. Yanliang Zhang (now at GMZ), Liang Han, Emmanuel Sachdeva, Ed Castillo, Matt Belley, Wei Jiang.

- **Collaborators**

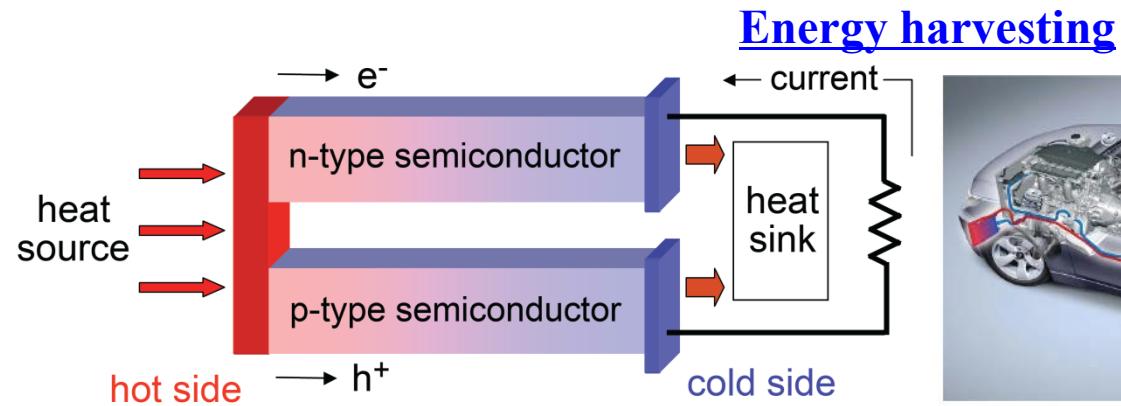
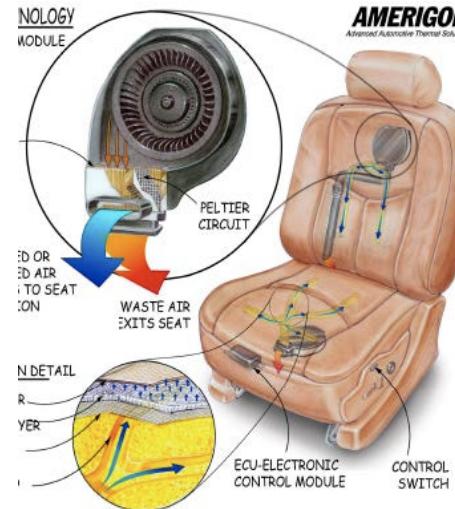
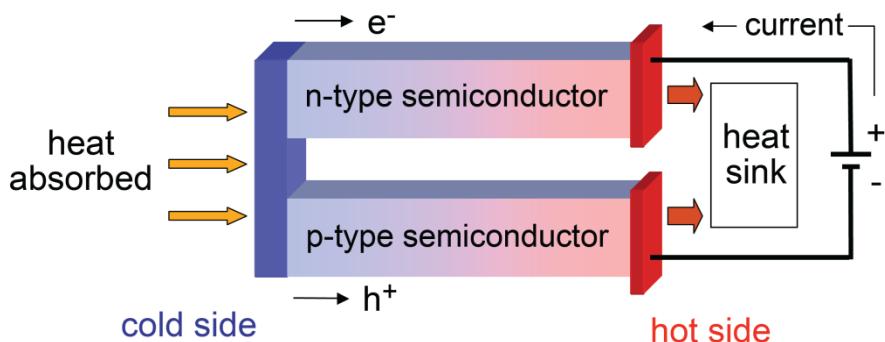
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- **Funding**

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- National Science Foundation (ECCS, CMMI, DMR, and other grants)
- NRI-NIST, and NY State

# Solid-state electrical $\leftrightarrow$ thermal conversion

## Heat management/refrigeration

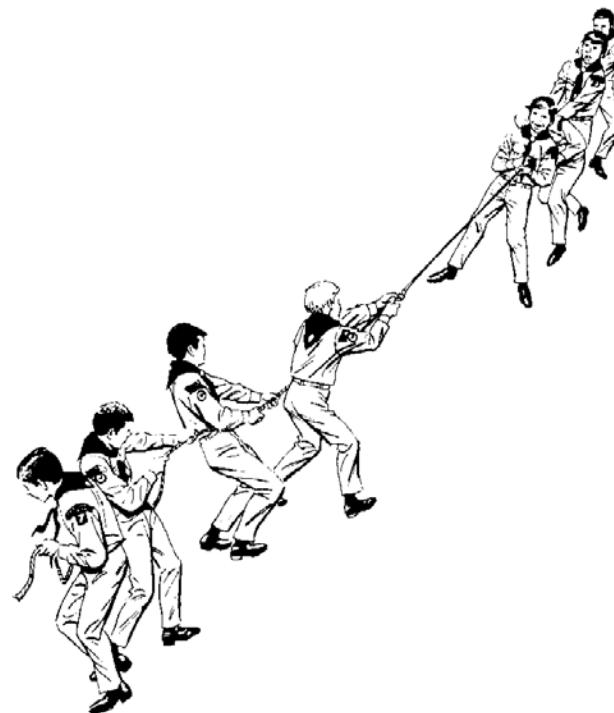
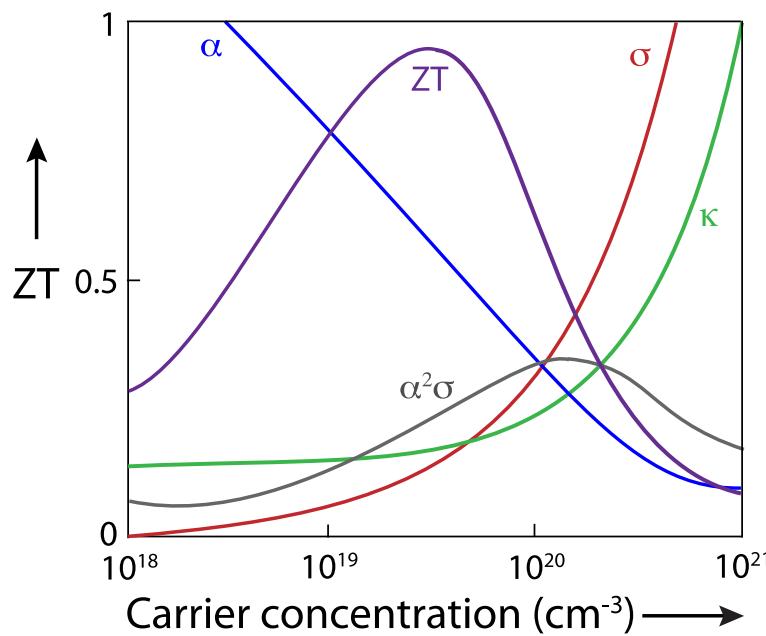
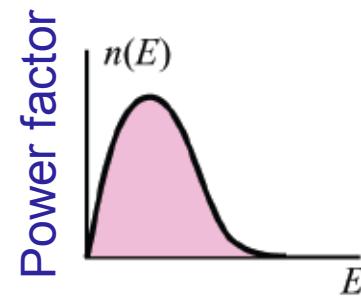
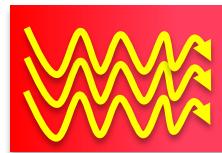


# Thermoelectrics, a tug-of-war of properties !

$$ZT = \frac{\alpha^2 \sigma}{\kappa} T$$

Thermal conductivity

$$= \kappa_L + \kappa_e$$



- Nano  $\rightarrow \kappa_L \downarrow$
- But  $\alpha^2 \sigma$  ?
- For p- and n-type ?

# High figure of merit nanostructured thermoelectrics

Best materials – Group V + VI, e.g.,  $\text{Bi}_2\text{Te}_3$

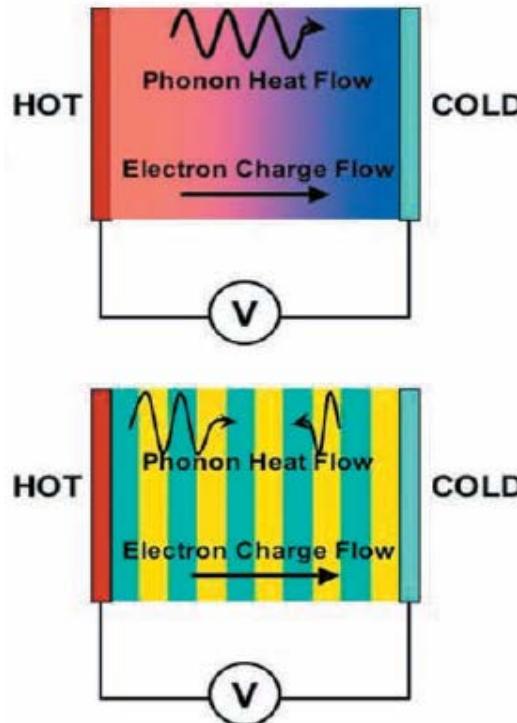
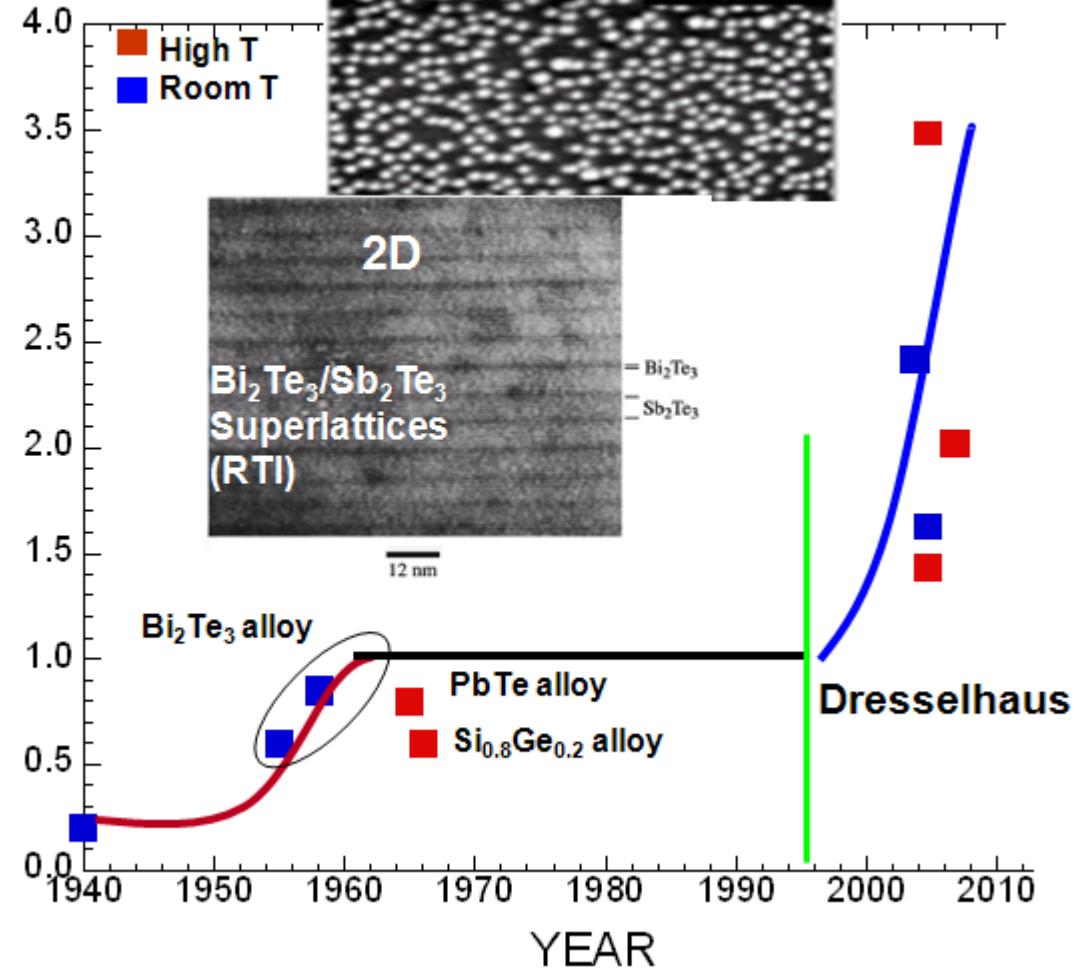
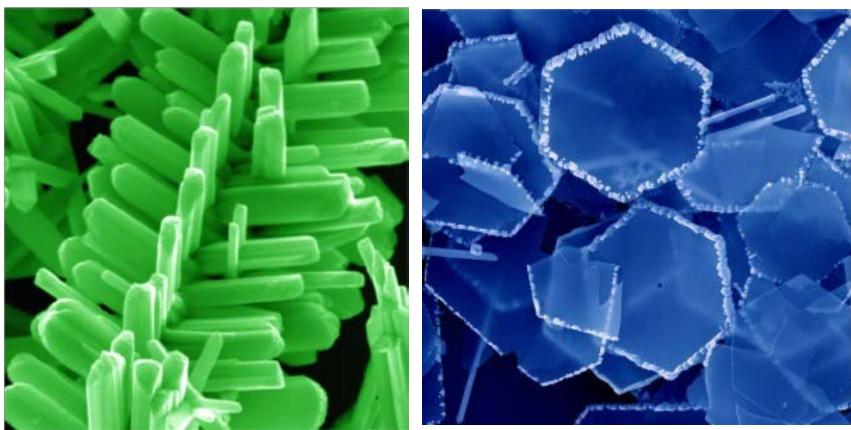
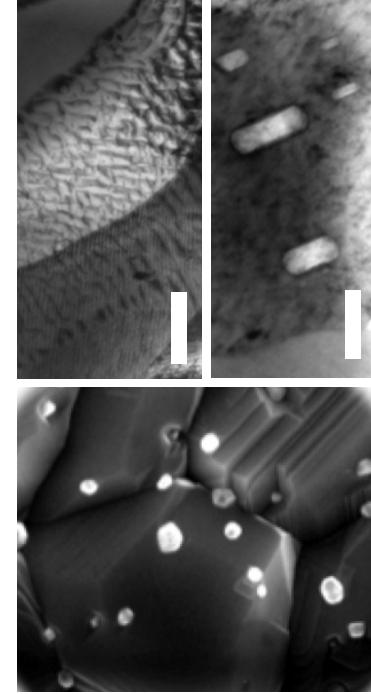
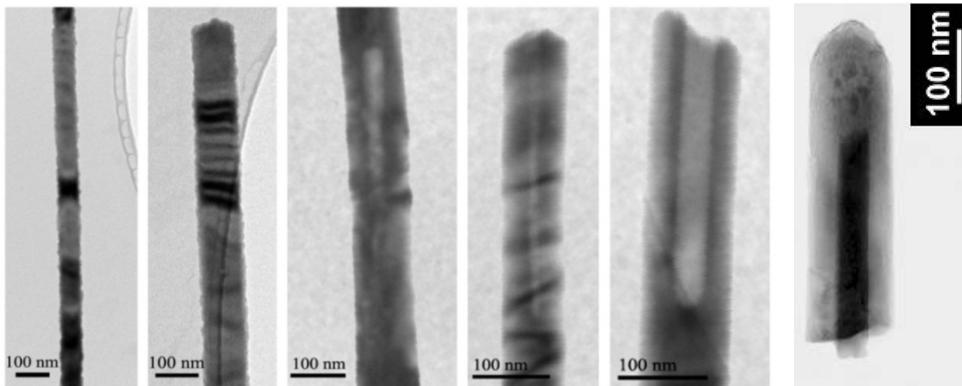
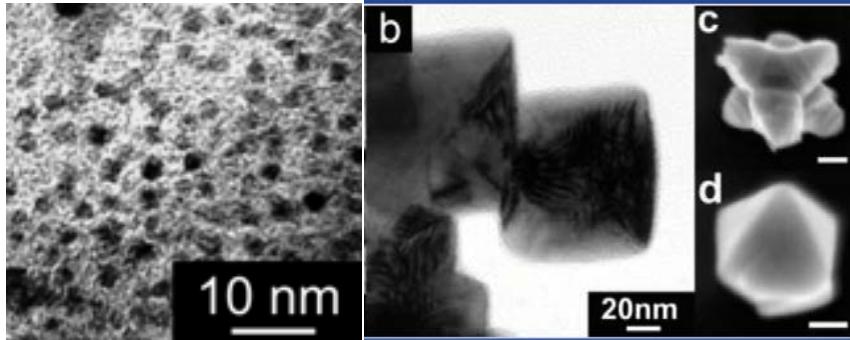
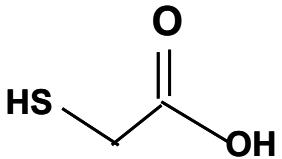


FIGURE OF MERIT



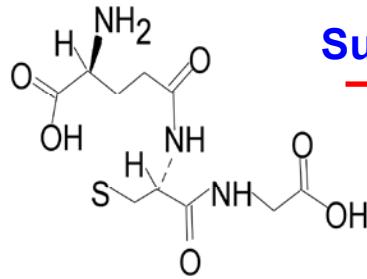
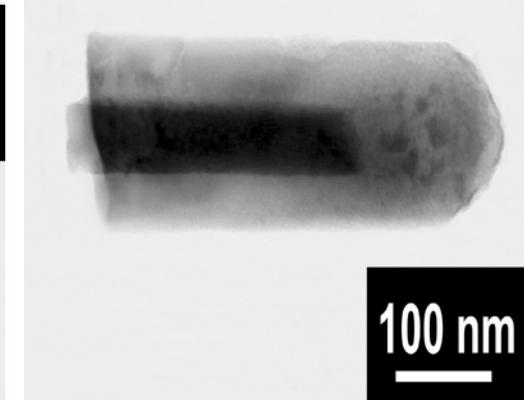
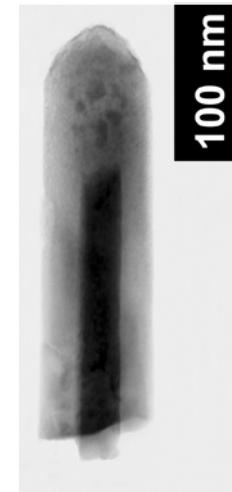
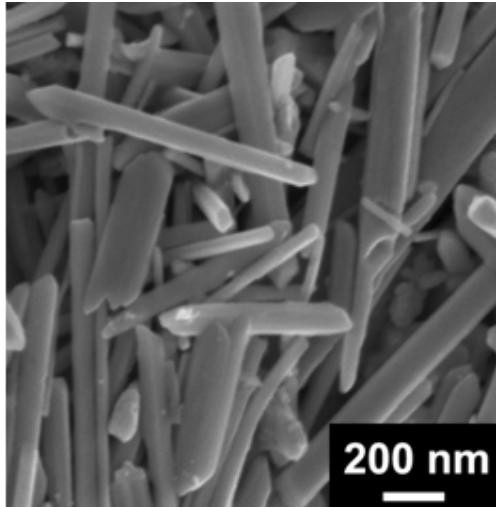
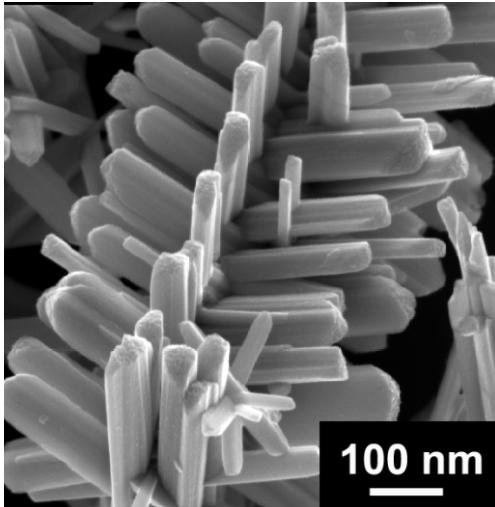
- **Quantum confinement**
  - Increase  $\sigma$  and  $\alpha$
- **Interface phonon scattering**
  - $\kappa$  decrease

# Surfactant-directed nanostructure sculpting and assembly



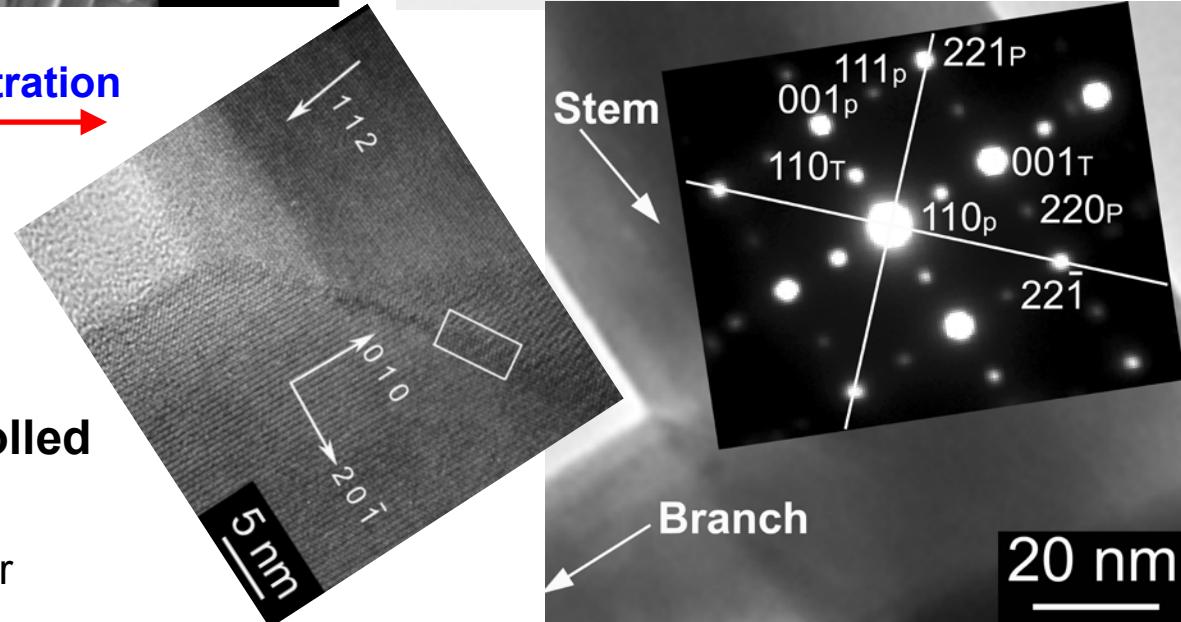
Adv. Mater. (2006-08); Chem Mater. (2008-11),  
Nano Lett (2010-11), J Phys Chem (2010), ACS Nano (2010), Nature Materials (2012)...

# Surfactant-induced branching through twinning



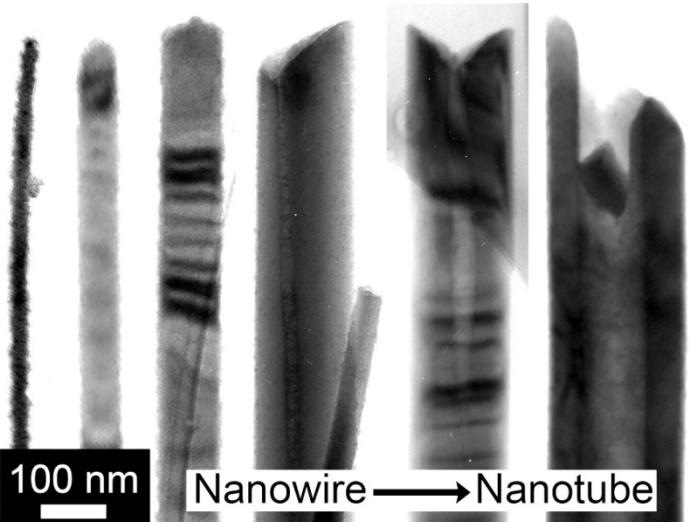
Surfactant concentration →

- Core-shell structures
- Nanoscale features controlled by beaker processing
  - Twining about  $(22\bar{1})$  mirror plane

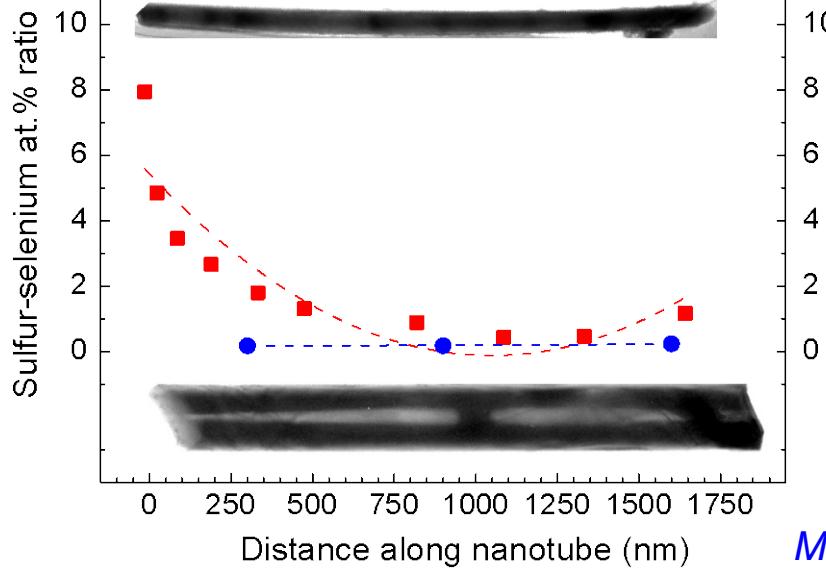
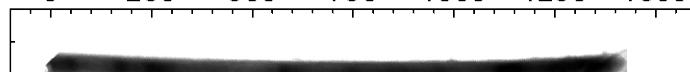


Purkayastha, Li, ..., Borca-Tasciuc, Ramanath, *Adv. Mater.* 20, 2679 (2008).

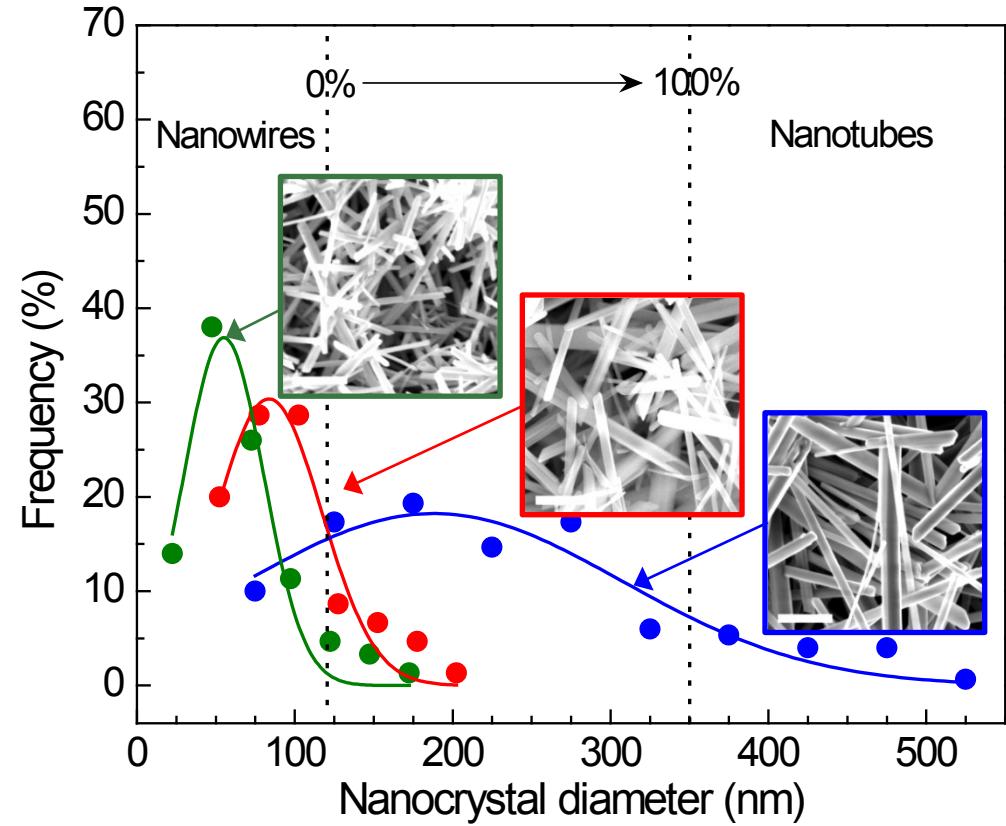
# Sulfurized antimony selenide: nanowire → nanotube conversion



Distance along nanowire (nm)

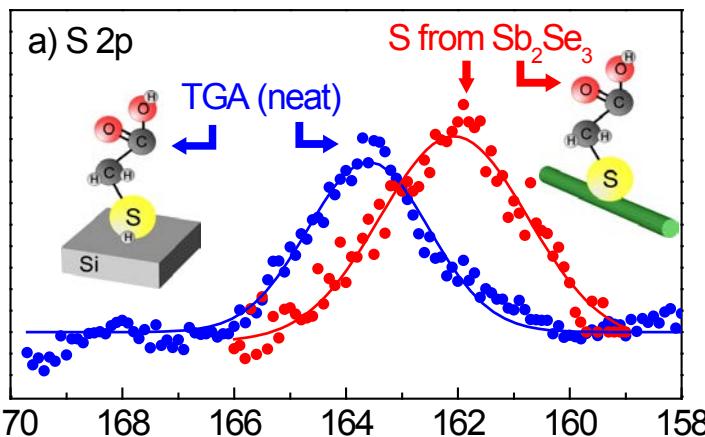
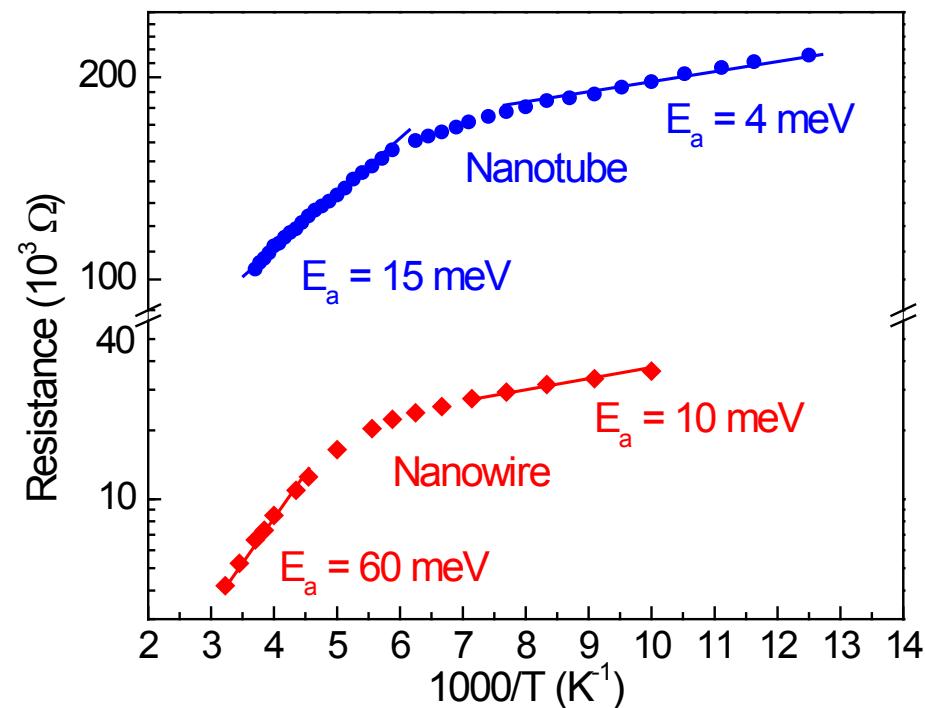
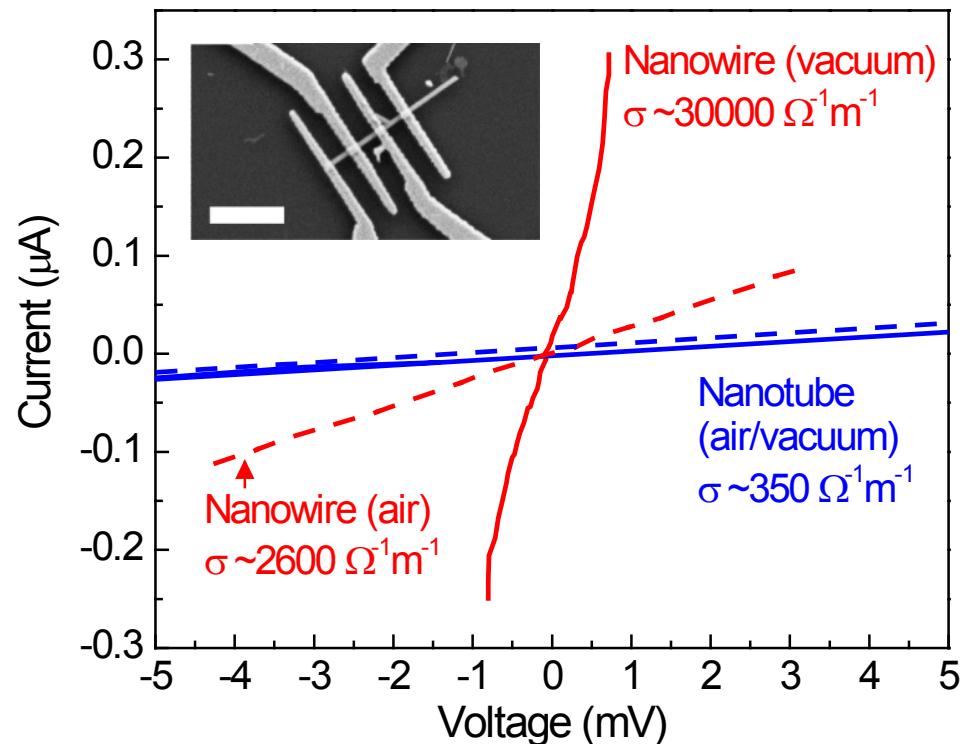


Mehta, ..., Ramanath, *Nano. Lett.* 10, 4417 (2010)



- Large  $\alpha \sim 1600 \mu\text{V/K}$
- Low  $\sigma \sim 10^{-2} - 10^{-5} \Omega^{-1}\text{m}^{-1}$
- ↑ Microwave dose: nanowire → nanotube
- TGA → sulfurization

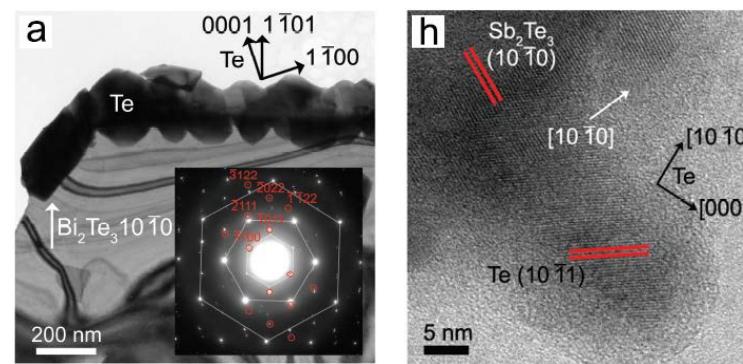
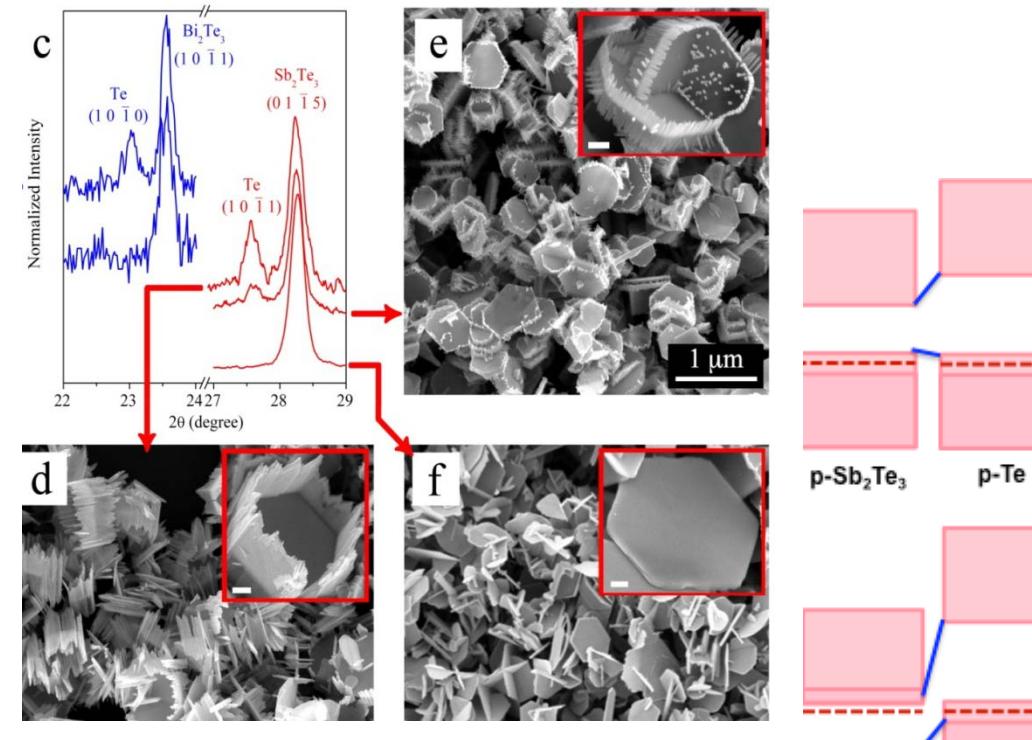
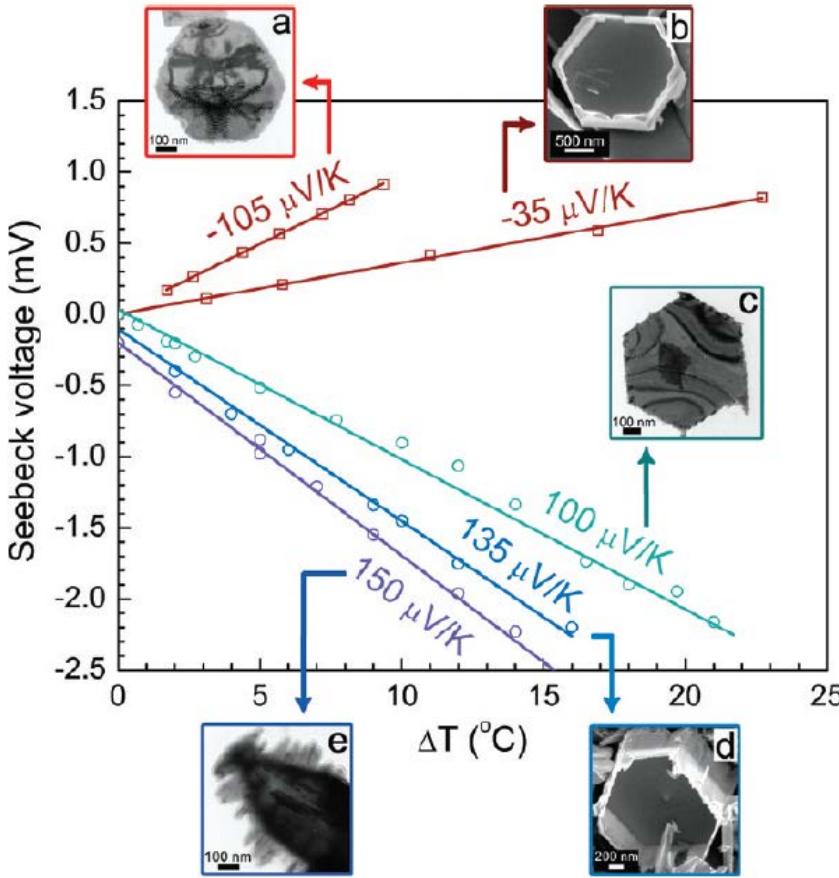
# Colossal electrical conductivity enhancement in $Sb_2Se_3$



- $10^4$ - $10^{10}$  higher than bulk; get  $\sigma \sim 10 - 10^5 \Omega^{-1}\text{m}^{-1}$
- Only nanowires (S gradients) show
  - high  $\sigma$  and ambient sensitivity
  - Shallow dopant levels from sulfur-surface states

Mehta, ..., Borca-Tasiuc, Ramanath, *Nano. Lett.* 10, 4417 (2010)

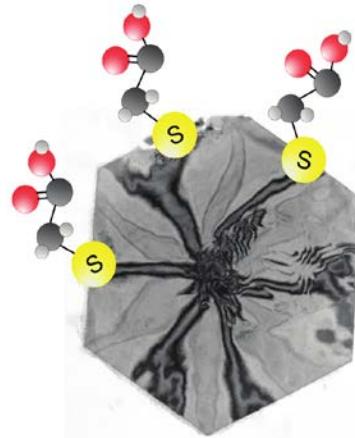
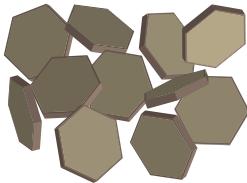
# Te-heterostructuring-induced $\alpha$ tuning



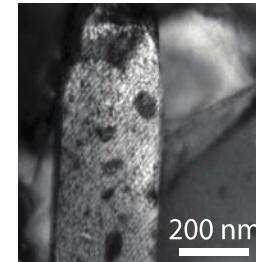
- $\alpha$  greater than bulk
  - Heterointerfaces
  - hot carrier filtering

Mehta, ..., Borca-Tasciuc, Ramanath, *ACS Nano* 4, 5055(2010)

# Single-crystal chalcogenide nanoplates and their assemblies



s



Google:  
Ramanath +  
microwave +  
thermoelectric

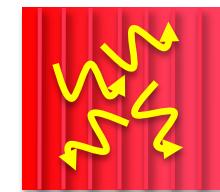
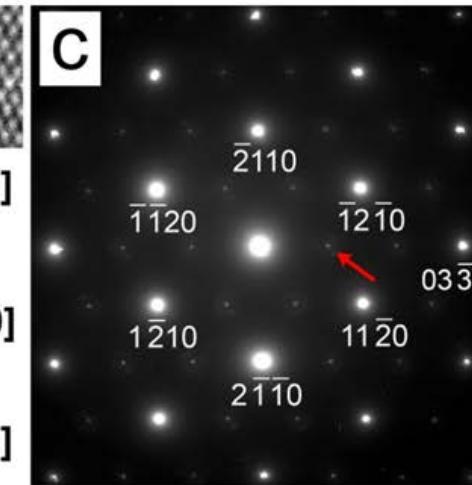
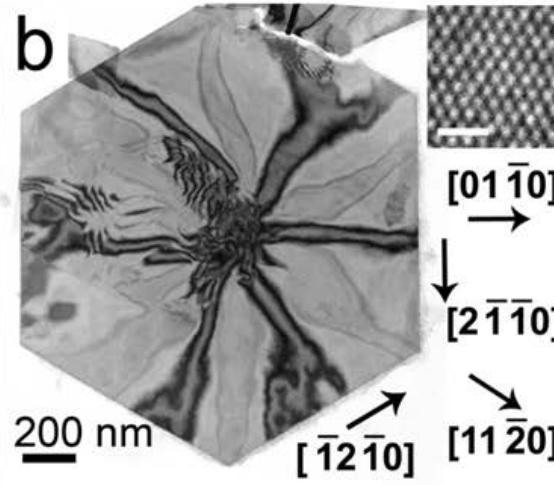
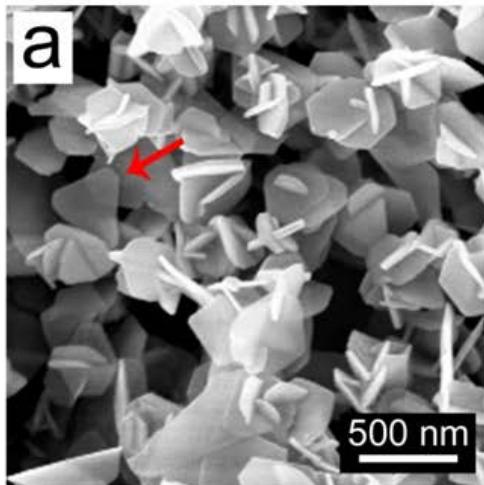


thermocaura<sup>inc</sup>

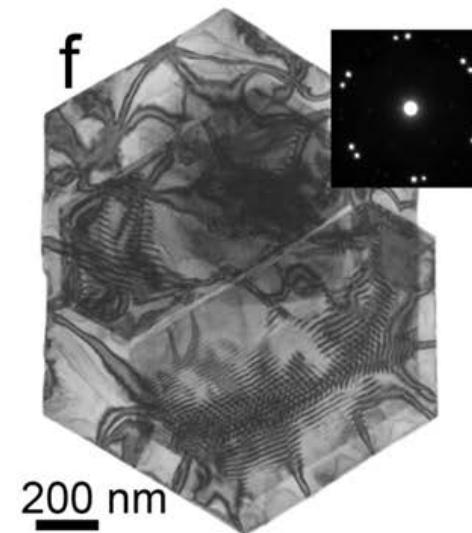
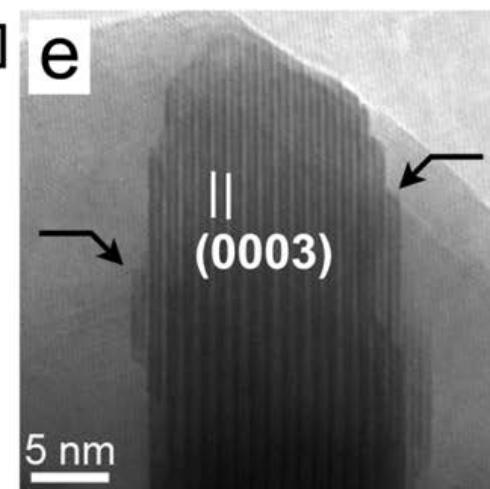
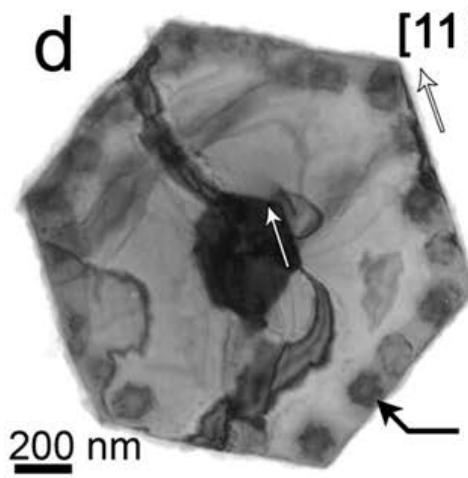
- **Shaping, sizing, doping and nanostructure/electronic structure control**
  - High ZT; both n- and p-type
  - Very low  $\kappa$  and potential for  $\alpha^2\sigma$  enhancement

*Mehta, ..., Borca-Tasciuc, Ramanath, Nature Mater. 11, 233-240 (2012).*

# Pnictogen chalcogenide nanoplate building blocks



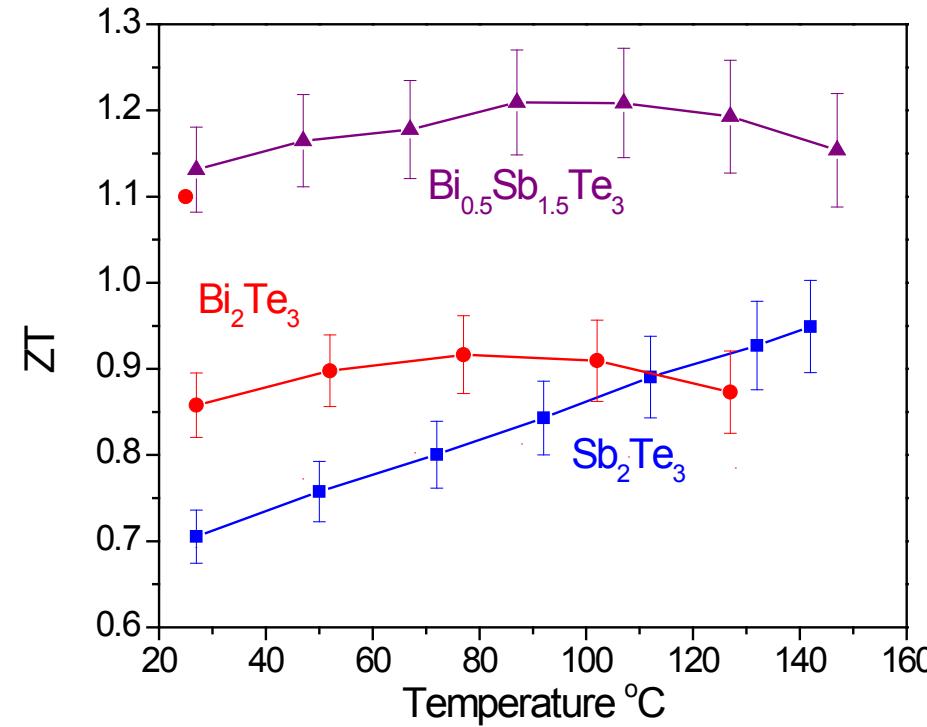
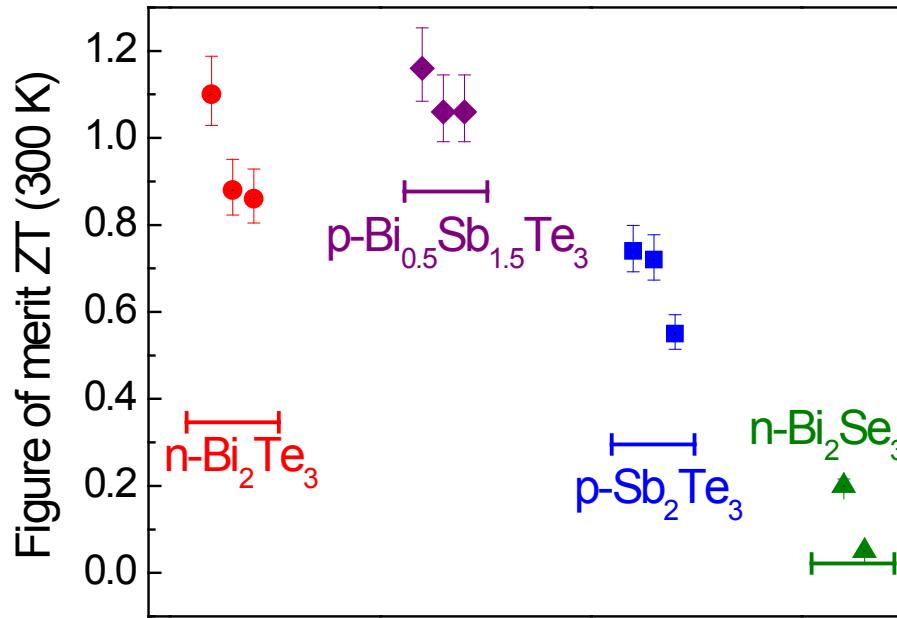
**Nano -  $\kappa_L$**



$\text{Bi}_2\text{Te}_3$   
 $\text{Bi}_2\text{Se}_3$   
 $\text{Sb}_2\text{Te}_3$

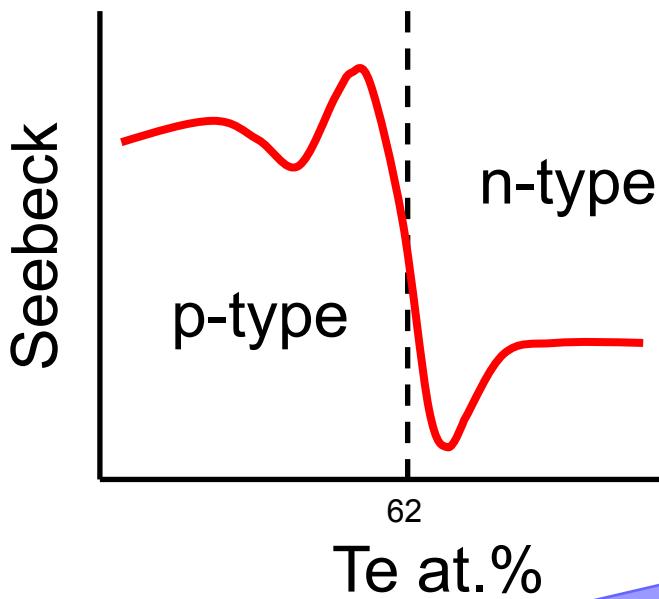
Mehta, ..., Borca-Tasciuc, Ramanath, *Nature Mater.* 11, 233-240 (2012).

# ZT increase for n- and p-type nanobulk thermoelectrics

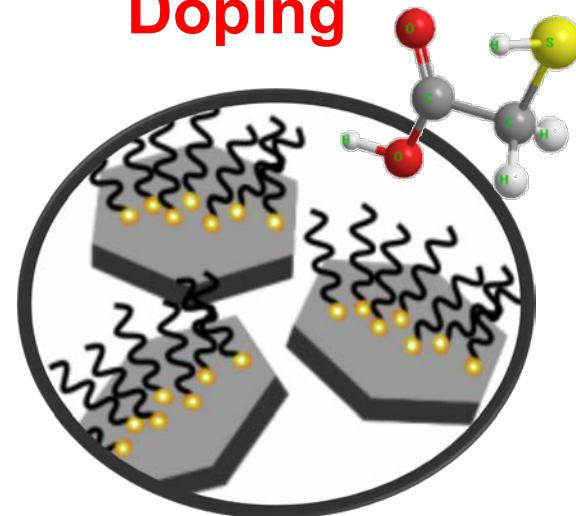


- ZT=1.1 n-Bi<sub>2</sub>Te<sub>3</sub>, ZT=0.75 p-Sb<sub>2</sub>Te<sub>3</sub> with no alloying!!
- ZT increases monotonically up to 0.95 p-Sb<sub>2</sub>Te<sub>3</sub> at 400 K
- Blind-samples verification at Marlow and Boston College

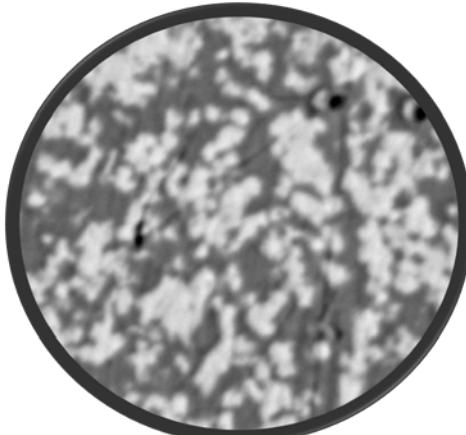
## Stoichiometry, composition



## Doping



## Nanobulk alloys/composites

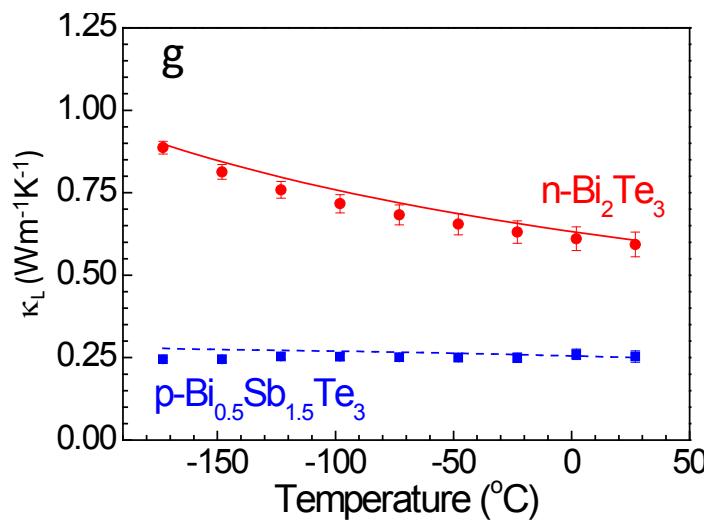
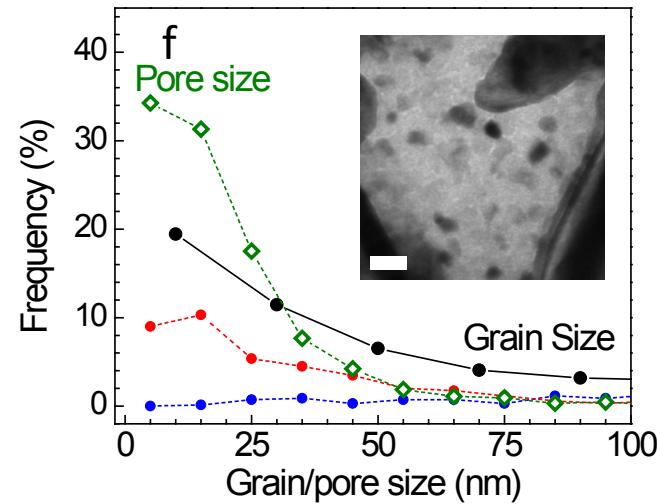
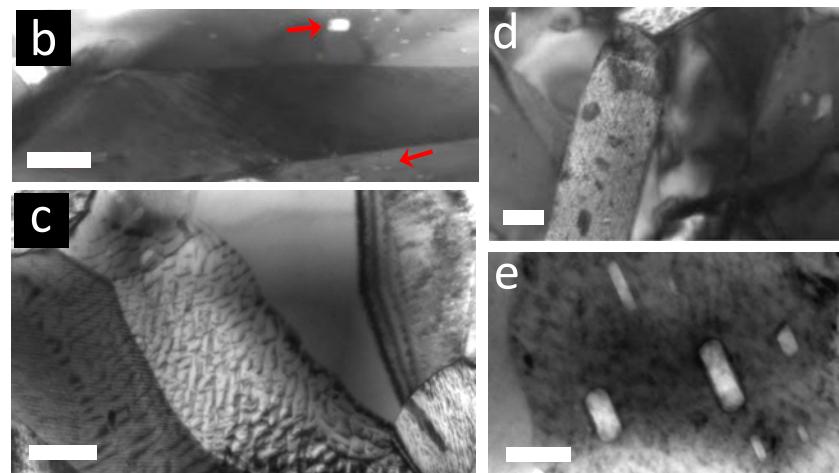
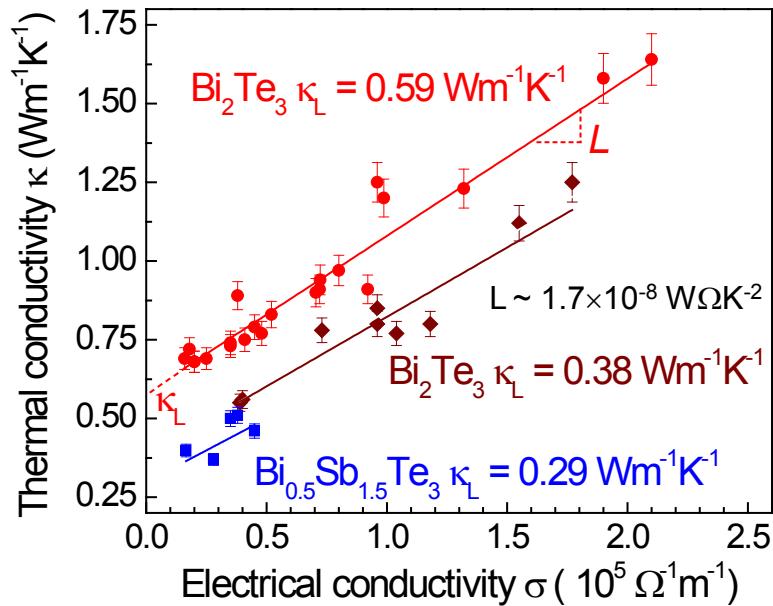


Higher ZT

## Heterostructuring

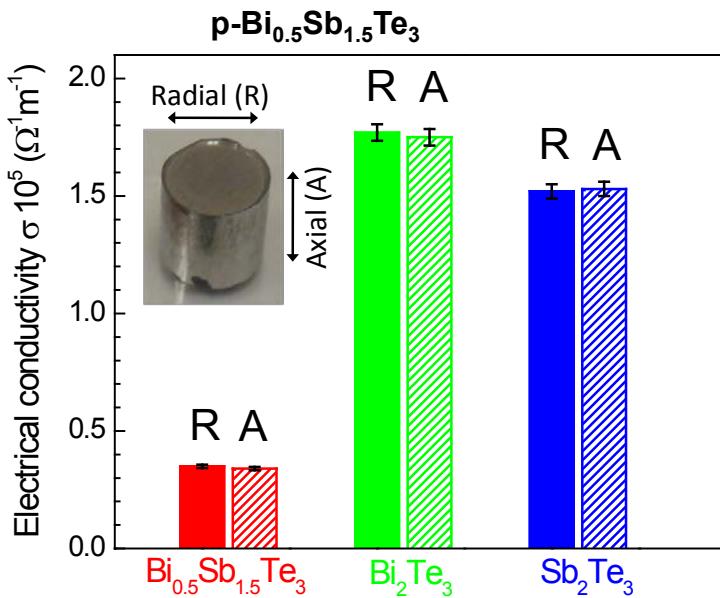
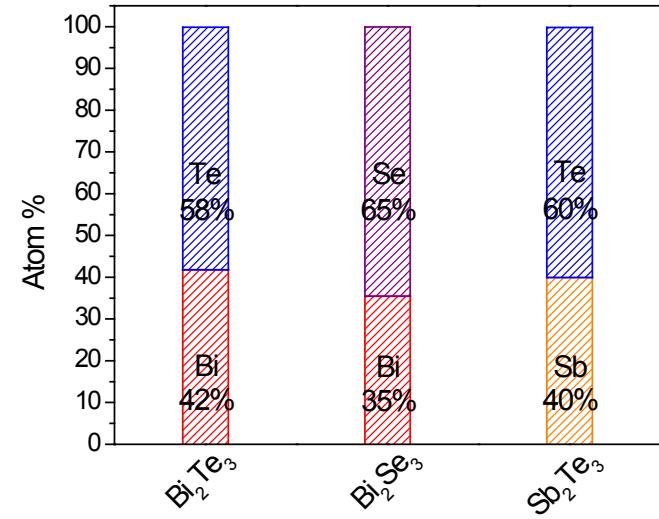
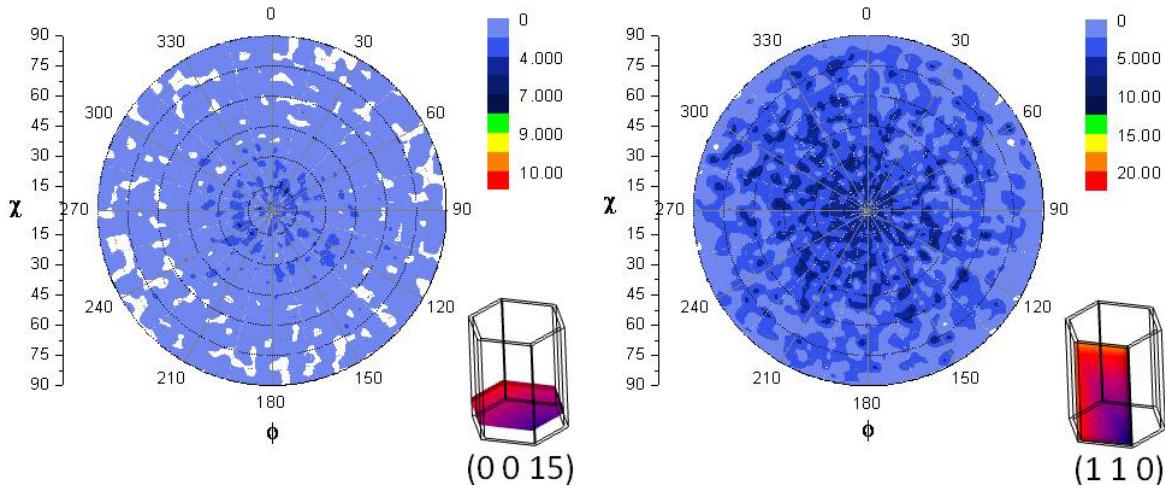


# 50-75% $\kappa_L$ diminution due to nanograins and nanopores

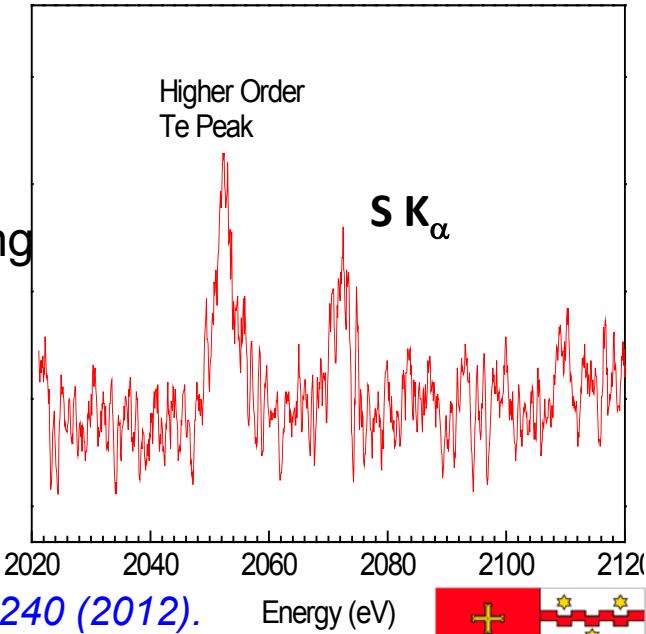


Mehta, ..., Borca-Tasciuc, Ramanath, *Nature Mater.* 11, 233-240 (2012).

# Isotropic properties of bulk-nano thermoelectrics



- Random texture
- Isotropic properties
- Near-stoichiometric
- 0.01-0.25 at.% S doping

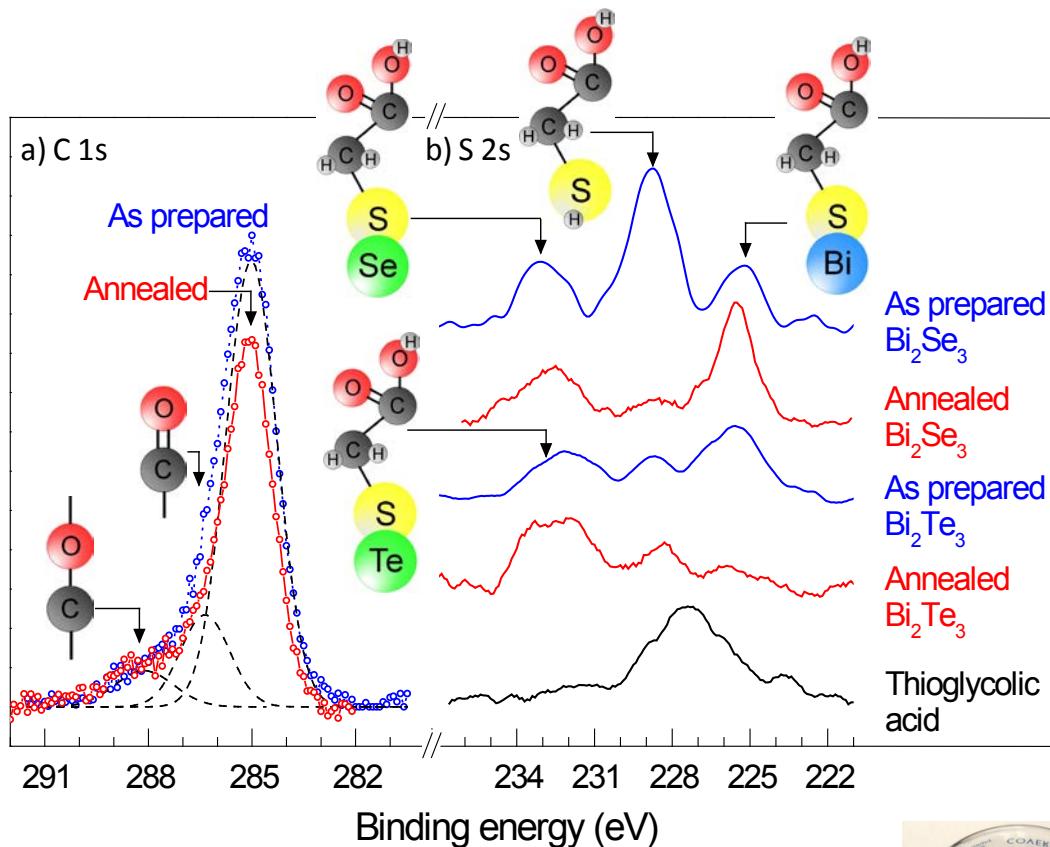


Mehta, ..., Borca-Tasciuc, Ramanath, *Nature Mater.* 11, 233-240 (2012).



# Sulfur doping and oxidation resistance

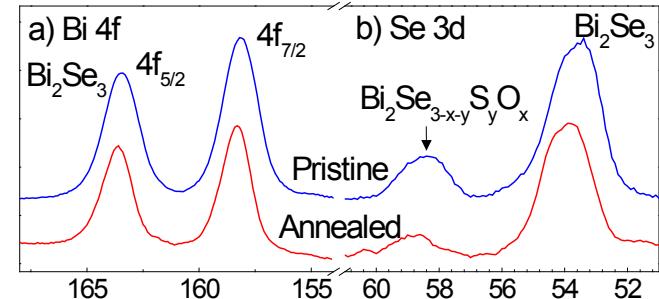
Intensity (a.u.)



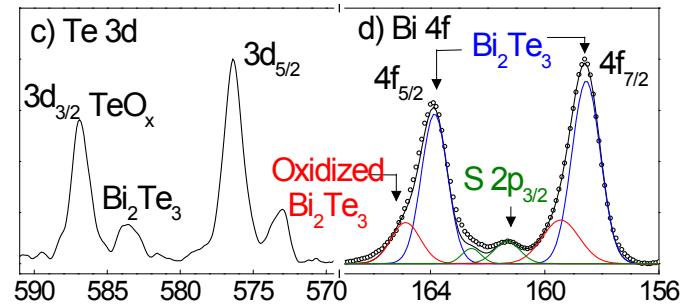
- Sulfur is in different chemical states**
- Surfactant capping inhibits oxidation**
  - No oxygen-free handling needed
  - Months/years storage in ambient



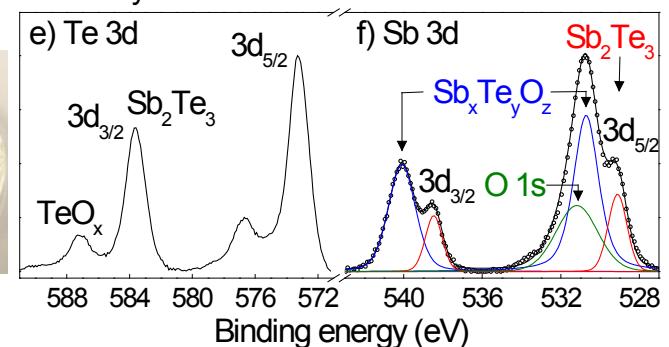
Bismuth Selenide



Bismuth Telluride

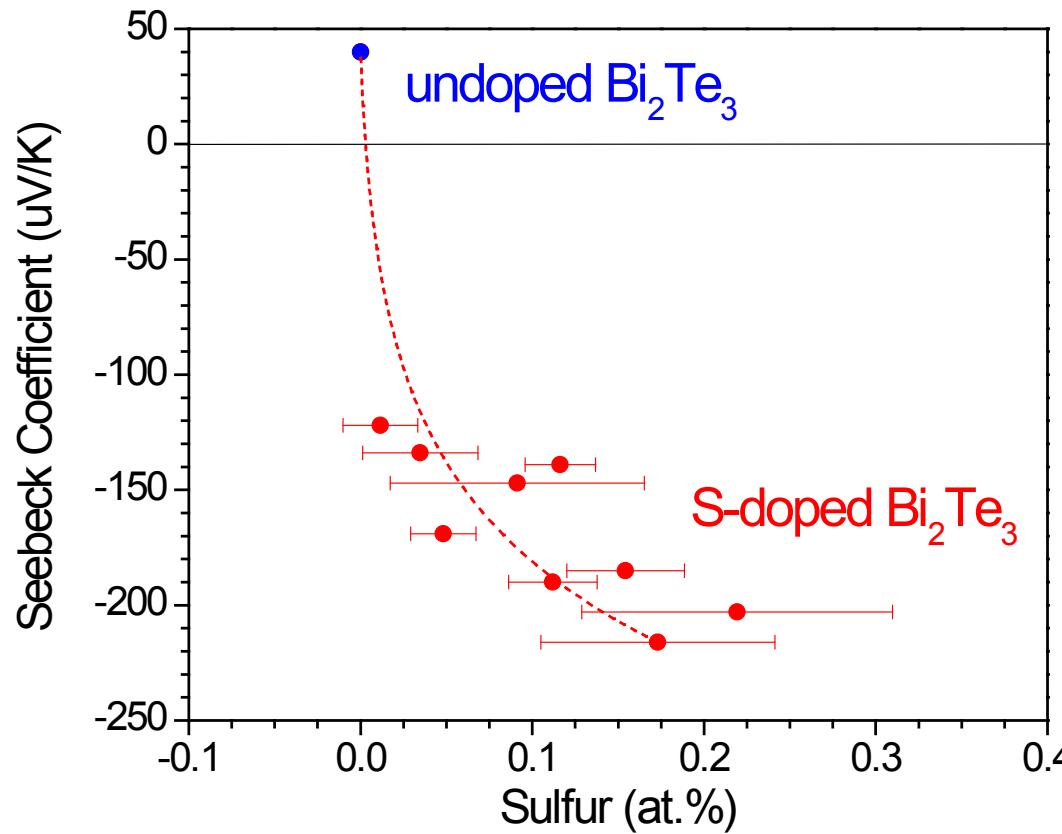


Antimony Telluride



Mehta, ..., Borca-Tasciuc, Ramanath, *Nature Mater.* 11, 233-240 (2012).

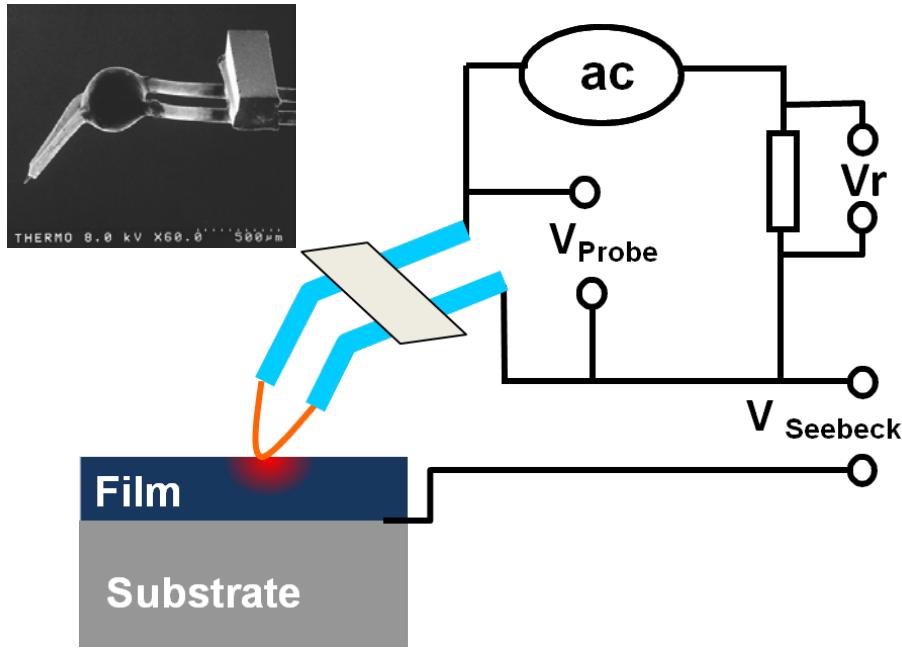
# Effects of sulfur doping on power factor



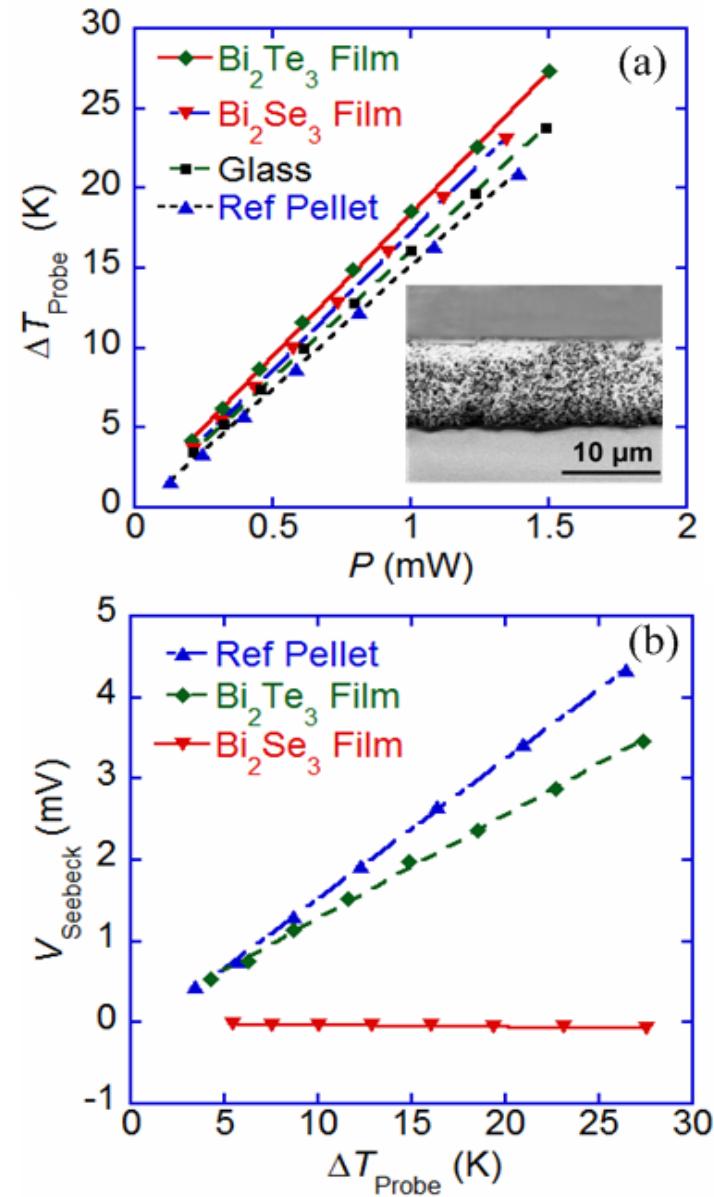
- **High  $\alpha$ , majority carrier reversal, high  $\sigma$** 
  - S doping, Fermi shift, DoS alteration near Fermi level
  - Non-linear dependence on carrier concentration

Mehta, ..., Borca-Tasciuc, Ramanath, *Nature Mater.* 11, 233-240 (2012).

# Scanning Thermoelectric $\mu$ -Probe

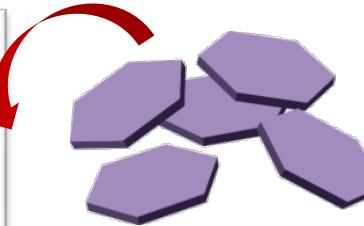
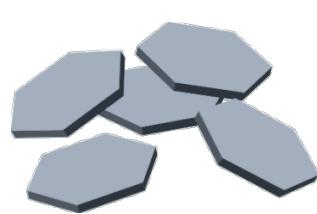


- Simultaneous  $\kappa$  and  $\alpha$  on films and nanobulk
- Non-contact  $\kappa$
- Validated using alternative techniques



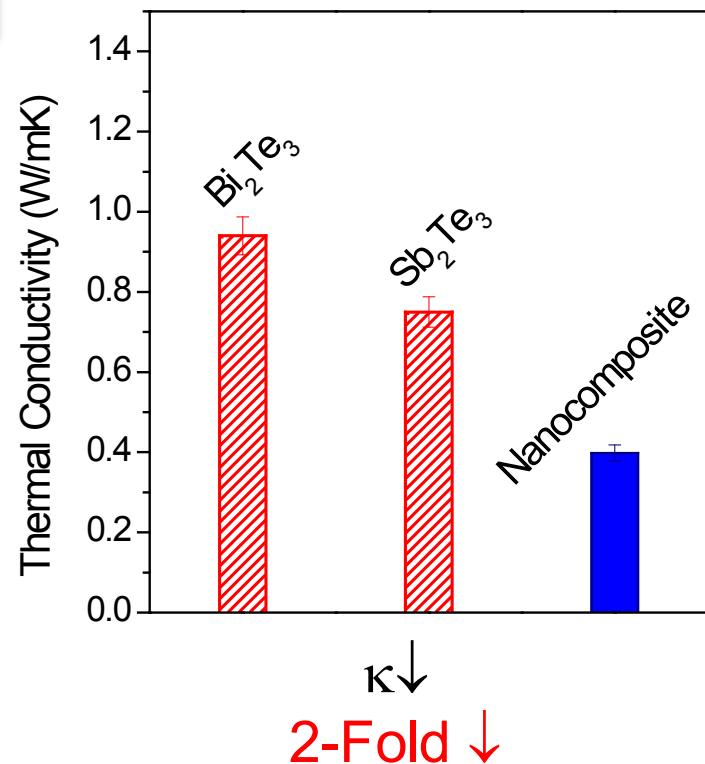
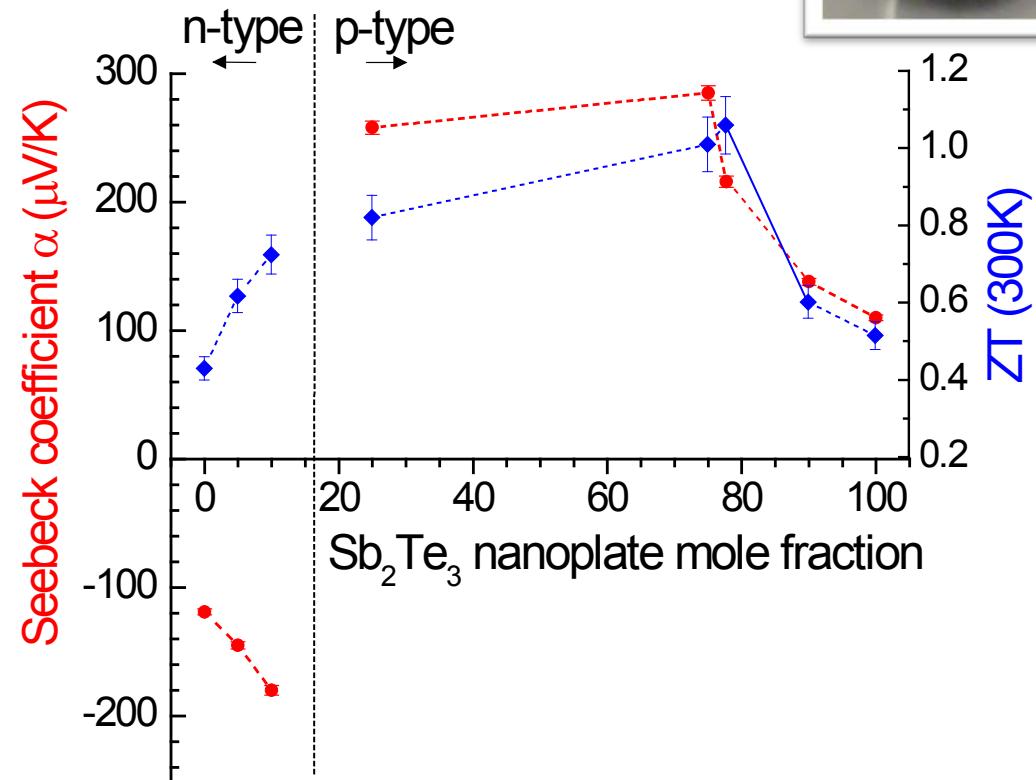
Zhang, ..., Ramanath, Borca-Tasciuc, *Appl. Phys. Lett.* 96, 062107 (2010). *Rev Sci Instrum.* (2011)

# Nanobulk composite alloys: $\alpha$ tuning, $\kappa_L$ decrease, ZT increase



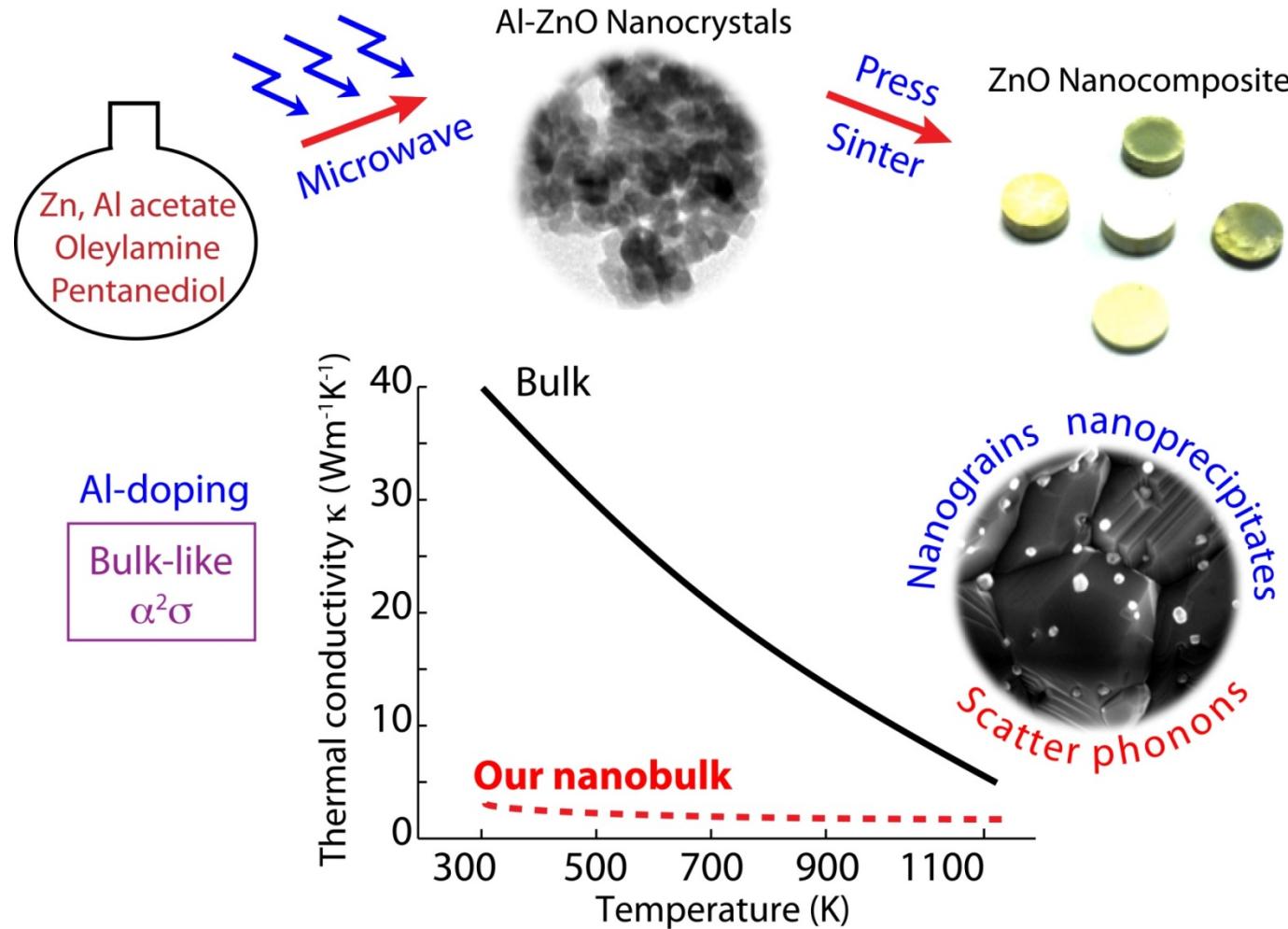
$\text{Bi}_2\text{Te}_3$  – n-type

$\text{Sb}_2\text{Te}_3$  – p-type



Mehta, ..., Borca-Tasciuc, Ramanath, *Nature Mater.* 11, 233-240 (2012).

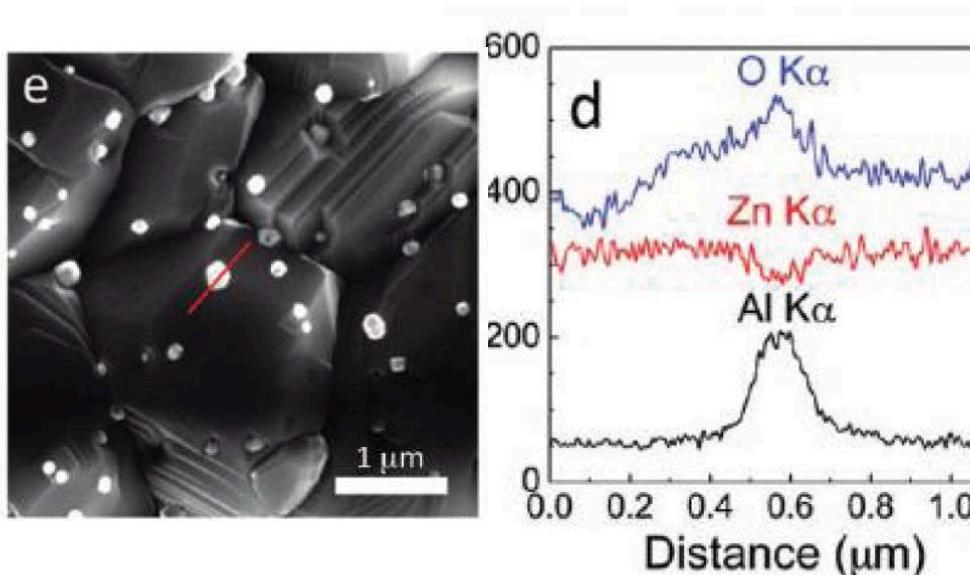
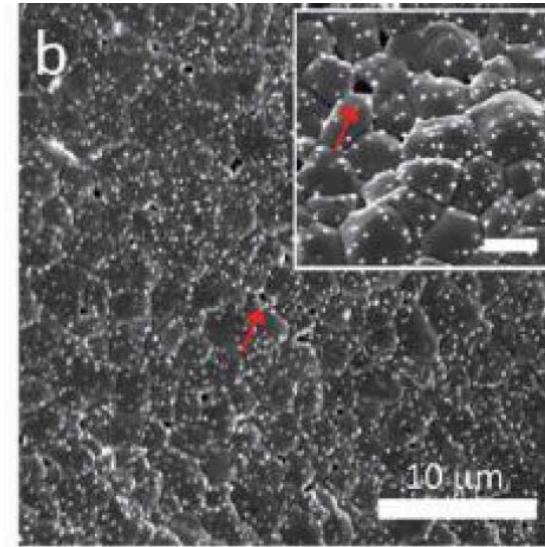
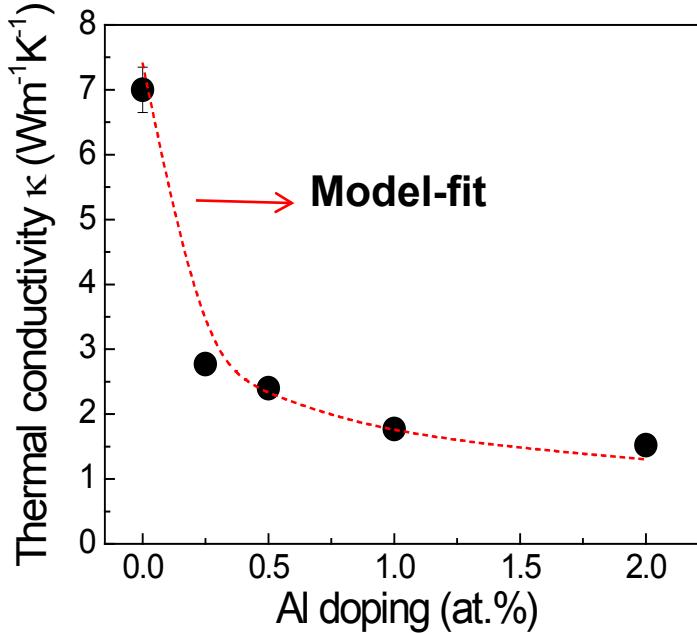
# Al-doped ZnO nanocomposites for high ZT @ high T



- Doping + nanostructuring → ZT=0.45 ....50% increase over bulk at 1000 K

Jood, Mehta..., Dou, Borca-Tasciuc, Ramanath, Nano. Lett. 11, 4337 (2011).

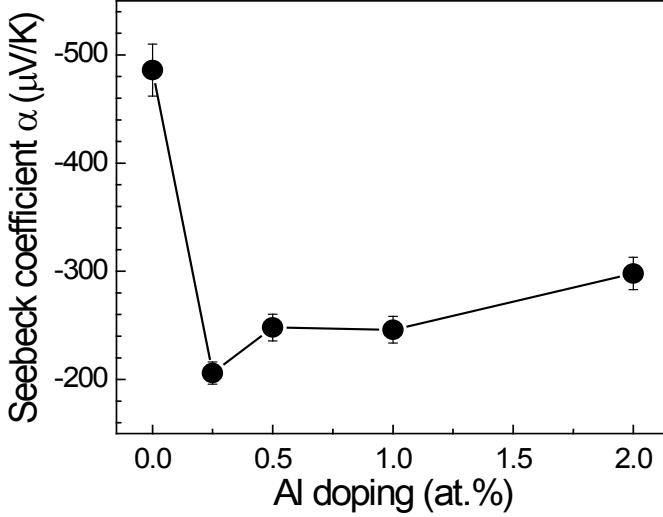
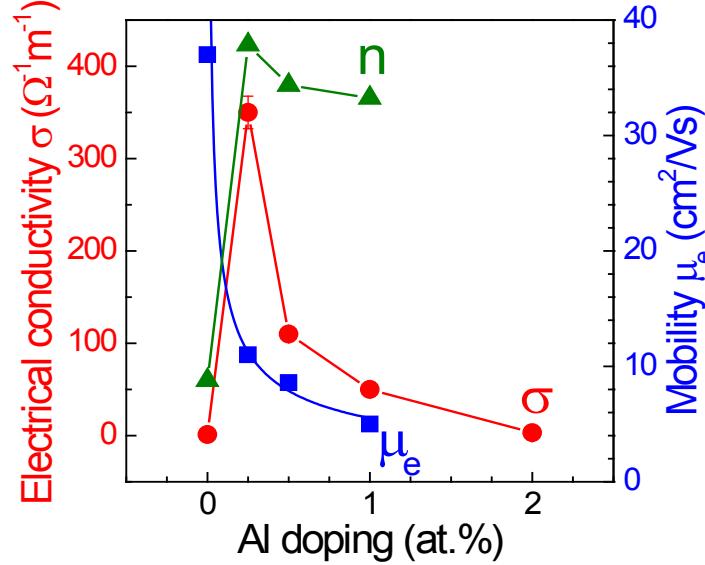
# Ultralow thermal conductivity due to nanostructuring



- Nanograins, nanoprecipitates, nanopores
  - 20-fold lower  $\kappa$  than bulk

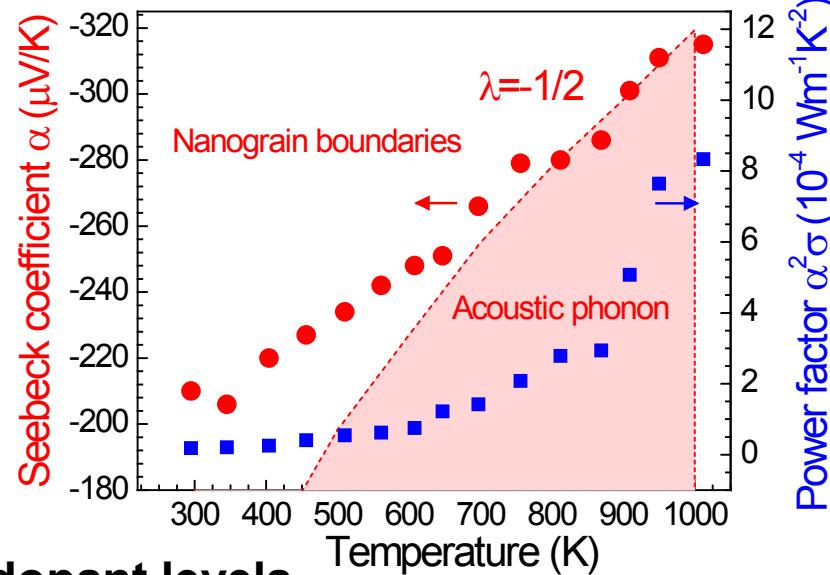
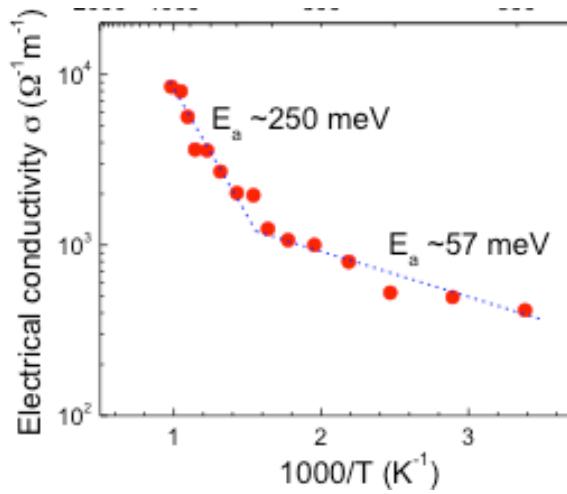
*Jood, Mehta..., Dou, Ramanath,  
Nano. Lett. 11, 4337 (2011).*

# Retention of high $\alpha$ and $\sigma$



- **Shallow dopant levels**

- Acoustic phonon scattering at high T—high  $\sigma$
- 40-95% higher  $\alpha$  than non-nano → high ZT



# Thank you !!!

